

SEMiX453GD176HDc



SEMiX® 33c

Trench IGBT Modules

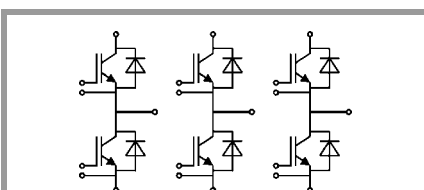
SEMiX453GD176HDc

Features

- Homogeneous Si
- Trench = Trenchgate technology
- $V_{CE(sat)}$ with positive temperature coefficient
- UL recognised file no. E63532

Typical Applications*

- AC inverter drives
- UPS
- Electronic welders



GD

Absolute Maximum Ratings				
Symbol	Conditions		Values	Unit
IGBT				
V _{CES}			1700	V
I _C	T _j = 150 °C	T _c = 25 °C	444	A
		T _c = 80 °C	315	A
I _{Cnom}			300	A
I _{CRM}	I _{CRM} = 2xI _{Cnom}		600	A
V _{GES}			-20 ... 20	V
t _{psc}	V _{CC} = 1000 V V _{GE} ≤ 20 V V _{CES} ≤ 1700 V	T _j = 125 °C	10	μs
T _j			-55 ... 150	°C
Inverse diode				
I _F	T _j = 150 °C	T _c = 25 °C	545	A
		T _c = 80 °C	365	A
I _{Fnom}			300	A
I _{FRM}	I _{FRM} = 2xI _{Fnom}		600	A
I _{FSM}	t _p = 10 ms, sin 180°, T _j = 25 °C		2900	A
T _j			-40 ... 150	°C
Module				
I _{t(RMS)}			600	A
T _{stg}			-40 ... 125	°C
V _{isol}	AC sinus 50Hz, t = 1 min		4000	V

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
IGBT						
V _{CE(sat)}	I _C = 300 A V _{GE} = 15 V chiplevel	T _j = 25 °C		2	2.45	V
		T _j = 125 °C		2.45	2.9	V
V _{CE0}	V _{GE} = 15 V	T _j = 25 °C		1	1.2	V
		T _j = 125 °C		0.9	1.1	V
r _{CE}		T _j = 25 °C		3.3	4.2	mΩ
		T _j = 125 °C		5.2	6.0	mΩ
V _{GE(th)}	V _{GE} =V _{CE} , I _C = 12 mA		5.2	5.8	6.4	V
I _{CES}	V _{GE} = 0 V	T _j = 25 °C	3			mA
	V _{CE} = 1700 V	T _j = 125 °C				mA
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz	26.4			nF
C _{oes}		f = 1 MHz	1.10			nF
C _{res}		f = 1 MHz	0.88			nF
Q _G	V _{GE} = - 8 V...+ 15 V		2799			nC
R _{Gint}	T _j = 25 °C		2.50			Ω
t _{d(on)}	V _{CC} = 1200 V I _C = 300 A	T _j = 125 °C	335			ns
t _r		T _j = 125 °C	70			ns
E _{on}	R _{G on} = 4.3 Ω R _{G off} = 4.3 Ω	T _j = 125 °C	215			mJ
t _{d(off)}		T _j = 125 °C	990			ns
t _f		T _j = 125 °C	150			ns
E _{off}		T _j = 125 °C	125			mJ
R _{th(j-c)}	per IGBT		0.071			K/W

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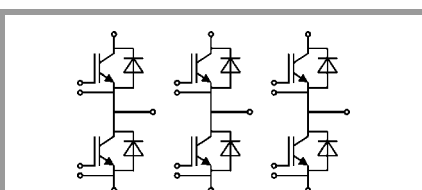
Features

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- Trench = Trenchgate technology
- $V_{CE(sat)}$ with positive temperature coefficient
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Typical Applications*

- AC inverter drives
- UPS
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Characteristics								
Symbol	Conditions		min.	typ.	max.	Unit		
Inverse diode								
V _F = V _{EC}	I _F = 300 A V _{GE} = 0 V chip	T _j = 25 °C		1.5	1.70	V		
		T _j = 125 °C		1.4	1.6	V		
V _{F0}		T _j = 25 °C	0.9	1.1	1.3	V		
		T _j = 125 °C	0.7	0.9	1.1	V		
r _F		T _j = 25 °C	1.3	1.3	1.3	mΩ		
		T _j = 125 °C	1.8	1.8	1.8	mΩ		
I _{RRM}	I _F = 300 A di/dt _{off} = 4700 A/μs V _{GE} = -15 V V _{CC} = 1200 V	T _j = 125 °C				A		
Q _{rr}		T _j = 125 °C				μC		
E _{rr}		T _j = 125 °C				mJ		
R _{th(j-c)}	per diode					0.11	K/W	
Module								
L _{CE}						20	nH	
R _{CC'+EE'}	res., terminal-chip	T _C = 25 °C				0.7	mΩ	
		T _C = 125 °C				1	mΩ	
R _{th(c-s)}	per module					0.014	K/W	
M _s	to heat sink (M5)		3				5	Nm
M _t		to terminals (M6)	2.5				5	Nm
								Nm
w						900	g	
Temperatur Sensor								
R ₁₀₀	T _C =100°C (R ₂₅ =5 kΩ)					493 ± 5%	Ω	
B _{100/125}	R _(T) =R ₁₀₀ exp[B _{100/125} (1/T-1/T ₁₀₀)]; T[K];					3550 ±2%	K	



GD

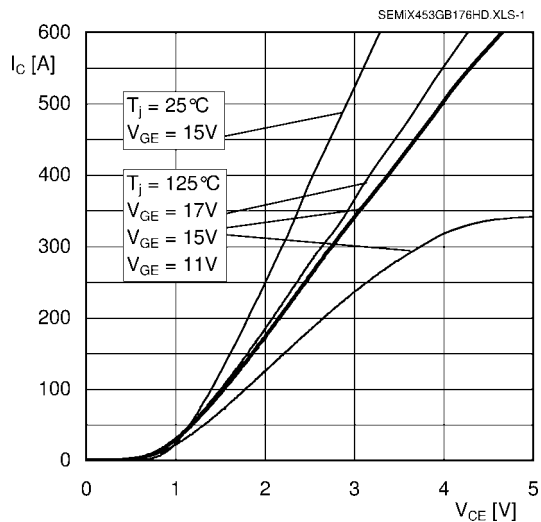


Fig. 1: Typ. output characteristic, inclusive $R_{CC'} + E_E$

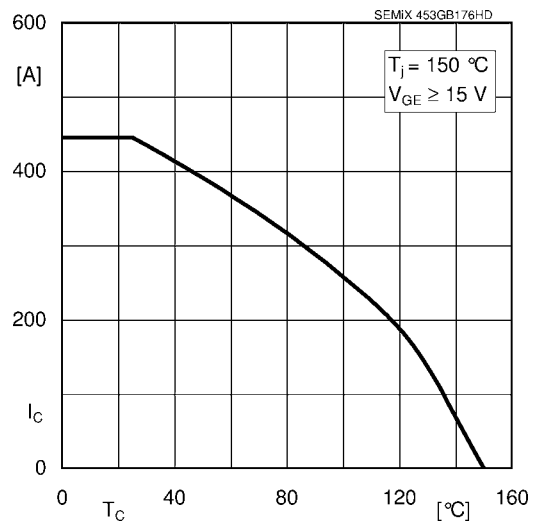


Fig. 2: Rated current vs. temperature $I_C = f(T_C)$

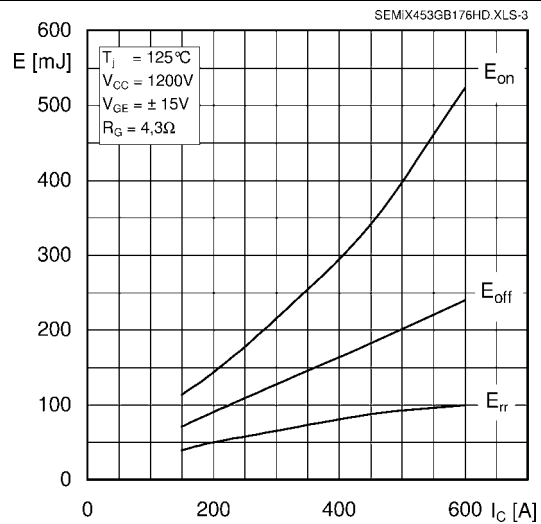


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

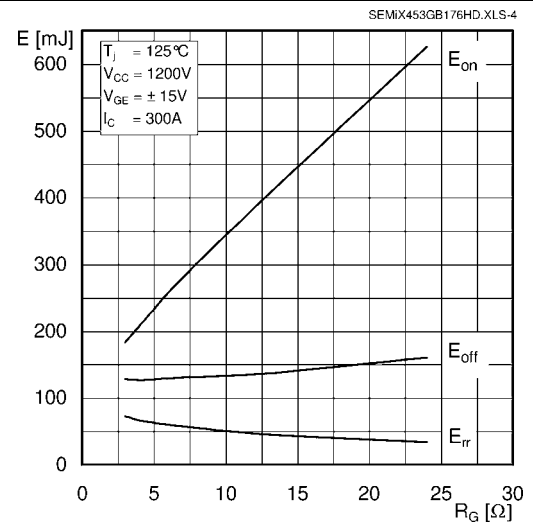


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

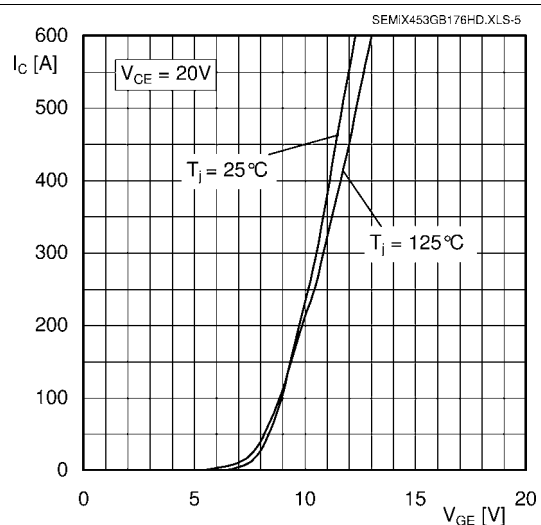


Fig. 5: Typ. transfer characteristic

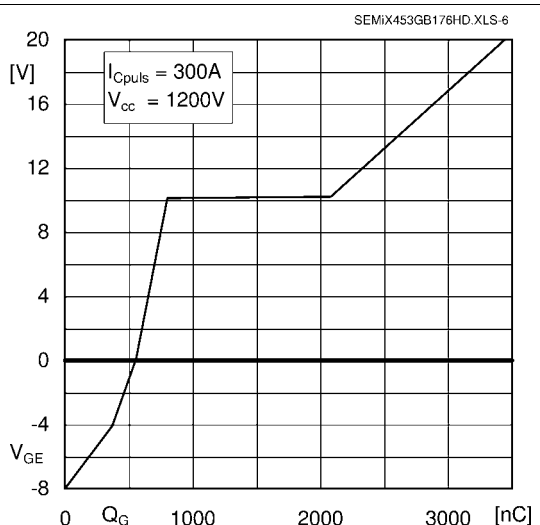
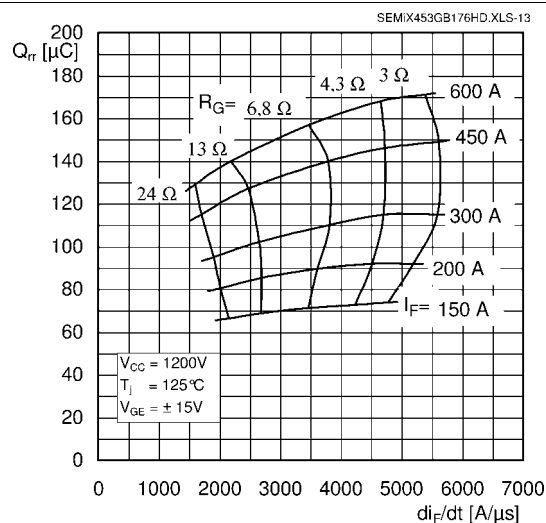
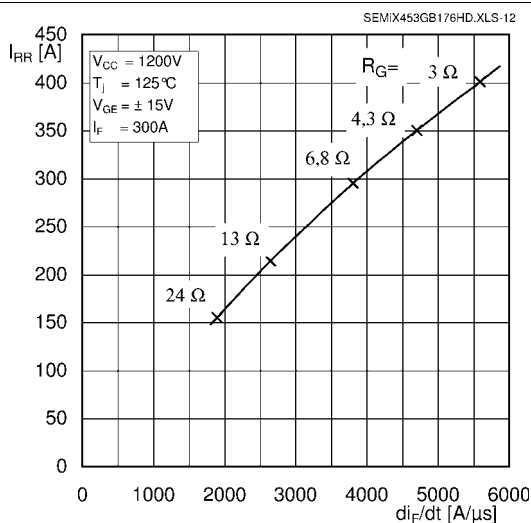
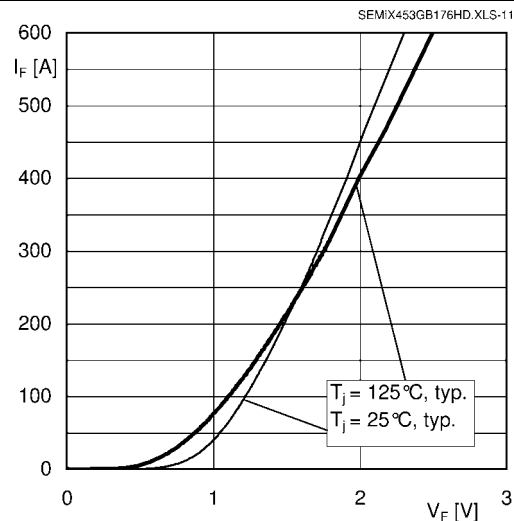
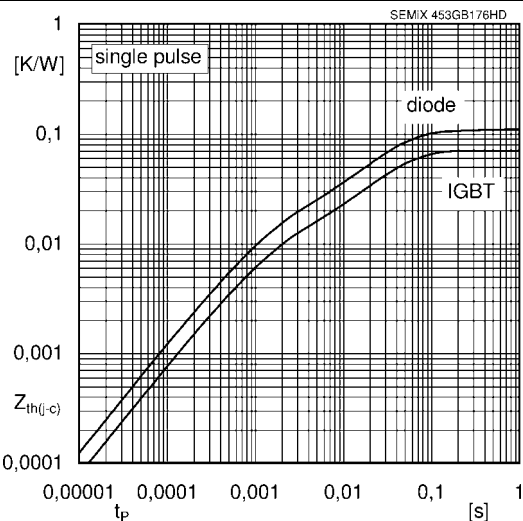
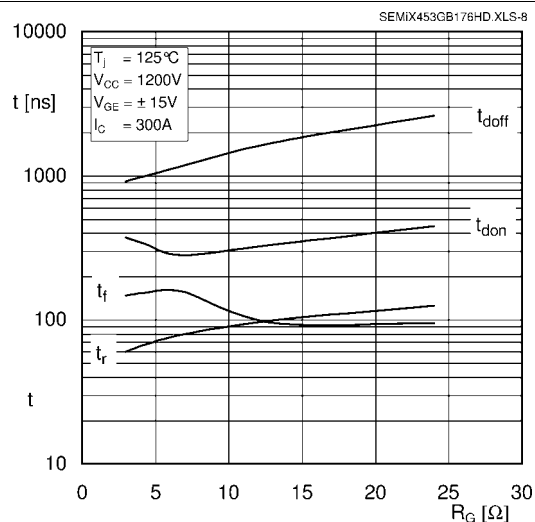
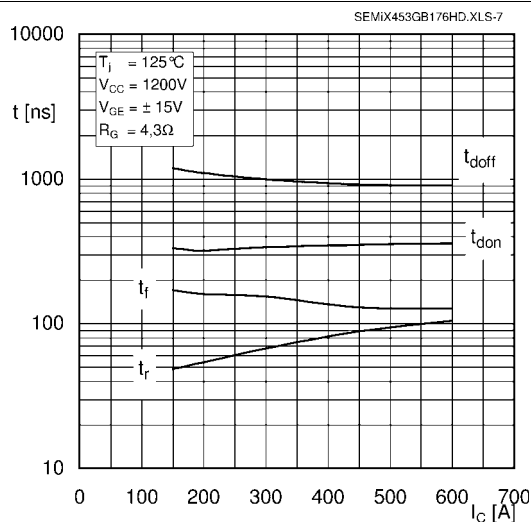
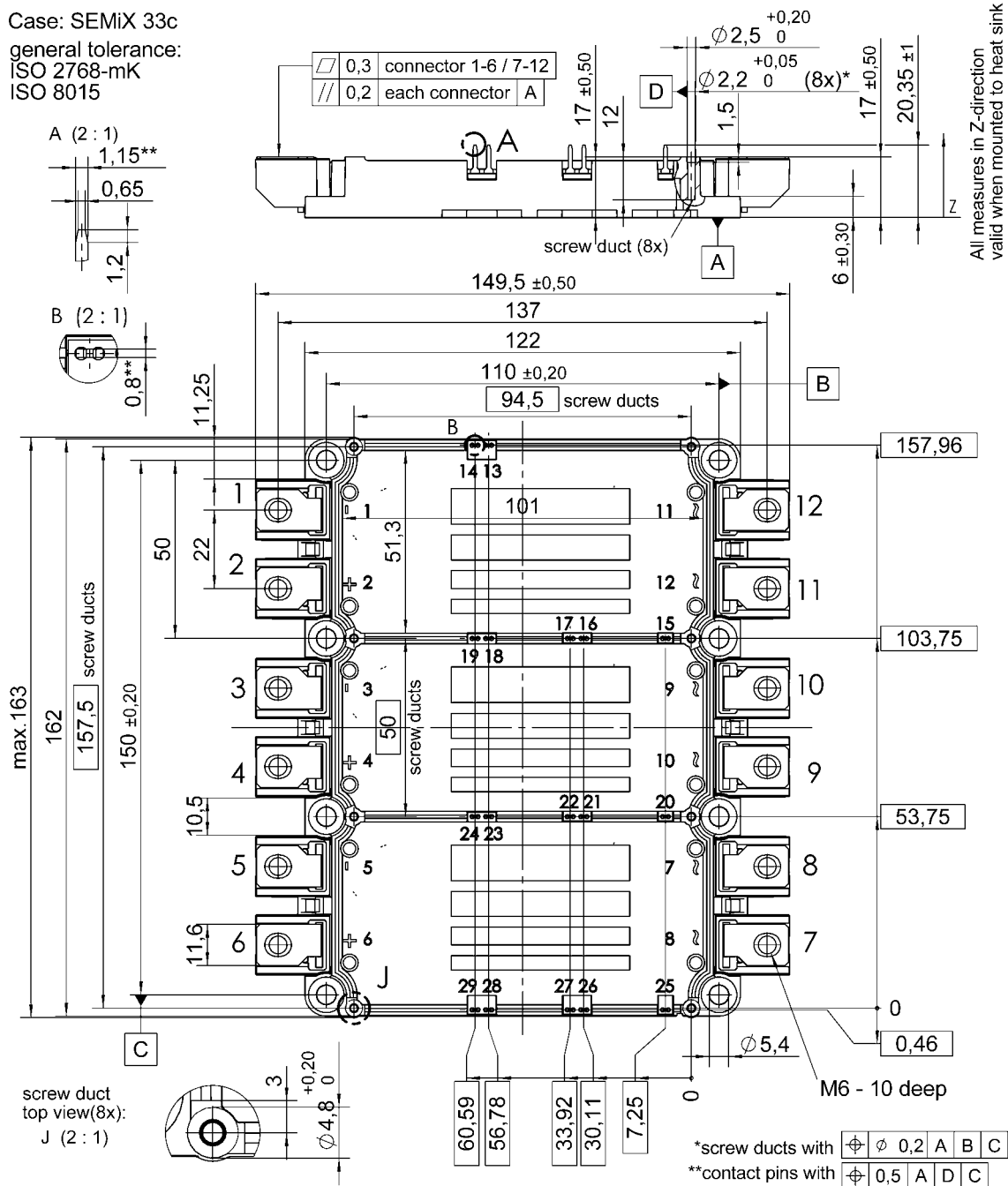


Fig. 6: Typ. gate charge characteristic

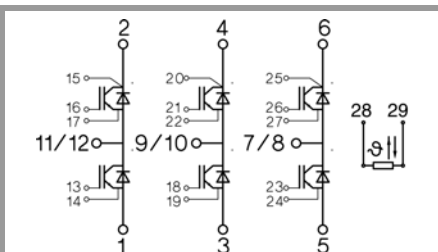


SEMiX453GD176HDc

Case: SEMiX 33c
general tolerance:
ISO 2768-mk
ISO 8015



SEMiX 33c



pinout

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.